## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of:

Shunji NAKAMURA

Serial Number: 10/003,304

Filed: December 6, 2001

SEMICONDUCTOR MEMORY DEVICE AND METHOD FOR

FABRICATING THE SAME

## PRELIMINARY AMENDMENT

Commissioner for Patents Washington, D.C. 20231

January 17, 2002

Group Art Unit: 2811

Examiner: Not Yet Assigned

Sir:

For:

Prior to examination on the merits, please amend the above-identified application as follows:

## **IN THE SPECIFICATION:**

Amend the specification as follows:

Please replace the paragraph beginning at page 17, line 18, with the following rewritten paragraph:

FIGs. 16A and 16B are sectional views of the semiconductor memory device according to the third embodiment, which explain the method (Part 2).

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